

# Silicon Germanium (SiGe) Substrates In Stock

*Silicon Germanium (SiGe) strained silicon for research/production.*

SOUTH BOSTON, MASSACHUSETTS, UNITED STATES, April 1, 2019 /EINPresswire.com/ -- We have the following [Silicon Germanium](#) Substrates in stock for research and production.

Pls see below for the [SiGe](#) on Si wafer general specification, Mini order qty. 10~15pcs, price depends on customer's requirements.

Substrate Description	Prime, Single crystal Silicon
Diameter	100mm, 150mm, 200mm
Thickness	Semi-Standard
Resistivity	1-100 Ohm.cm
Type	P-type/N-type



Why buy substrates in volume if you don't have to? Buy as few as one substrate and save!"

*Christian J. Baker*

Polish	One side epi polished (100)
Orientation	
Epitaxial layer	
Composition	SixGe1-x
Thickness	Upon-request
Dopant	None
Stress state	Strained/Relaxed

Christian Baker  
+1 617-413-1577  
[email us here](#)  
UniversityWafer, Inc.  
Visit us on social media:  
[Facebook](#)  
[Twitter](#)  
[LinkedIn](#)

This press release can be viewed online at: <http://www.einpresswire.com>

Disclaimer: If you have any questions regarding information in this press release please contact the company listed in the press release. Please do not contact EIN Presswire. We will be unable to assist you with your inquiry. EIN Presswire disclaims any content contained in these releases. © 1995-2019 IPD Group, Inc. All Right Reserved.